

# Modern photovoltaic technologies

## PHYS-609

### Part 1.4 III-V solar cells

- III-V solar cells
- multi-junction solar cells
- solar cells for space applications
- concentrated photovoltaics (CPV)

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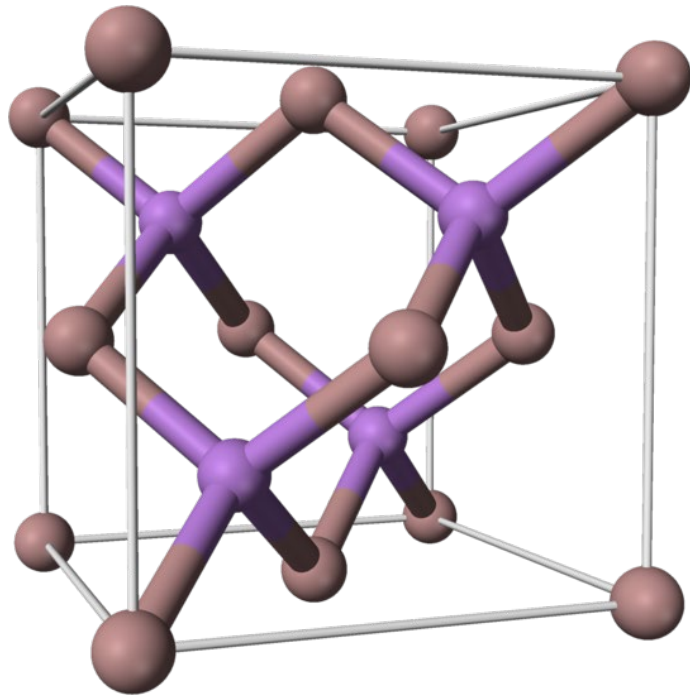
yaroslav.romanyuk@empa.ch



**Empa**

Materials Science and Technology

# III-V semiconductors



Cubic crystal structure of GaAs  
[www.wikipedia.com](http://www.wikipedia.com)

**GaAs ( $E_g = 1.42$  eV)**

GaP

InP

InAs

GaInAs

GaInP

AlGaInAs

AlGaInP

**Growth methods:**

Metalorganic Vapor Phase Epitaxy (MOVPE)  
Molecular beam epitaxy (MBE)

# III-V semiconductor bandgaps

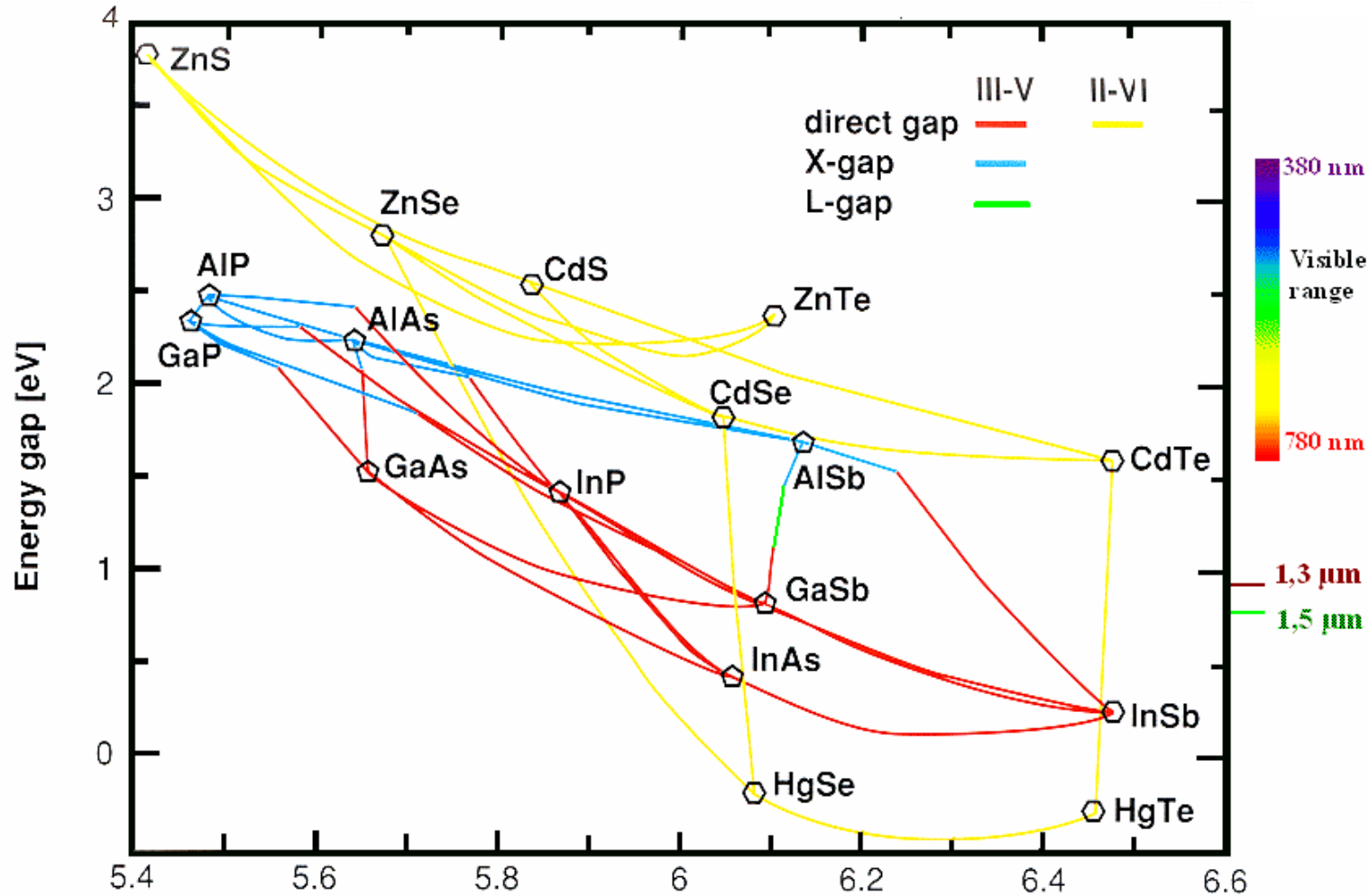
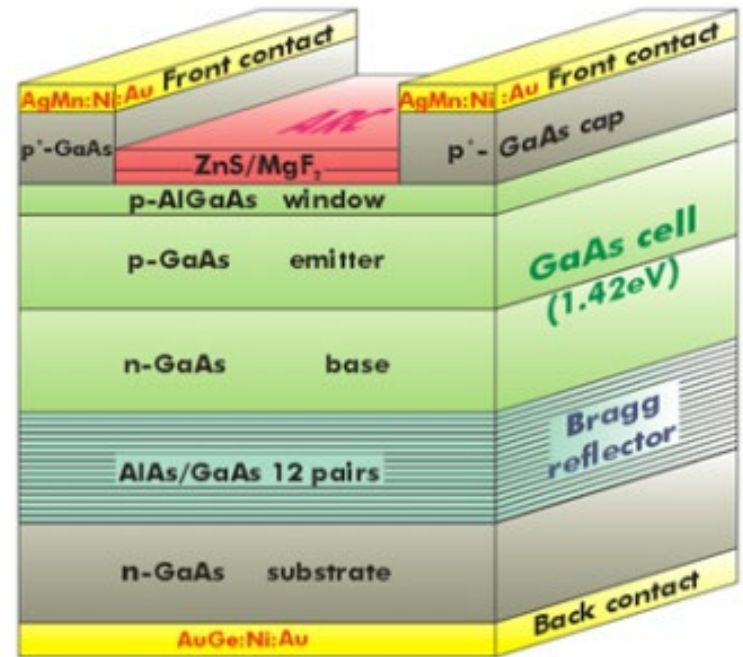
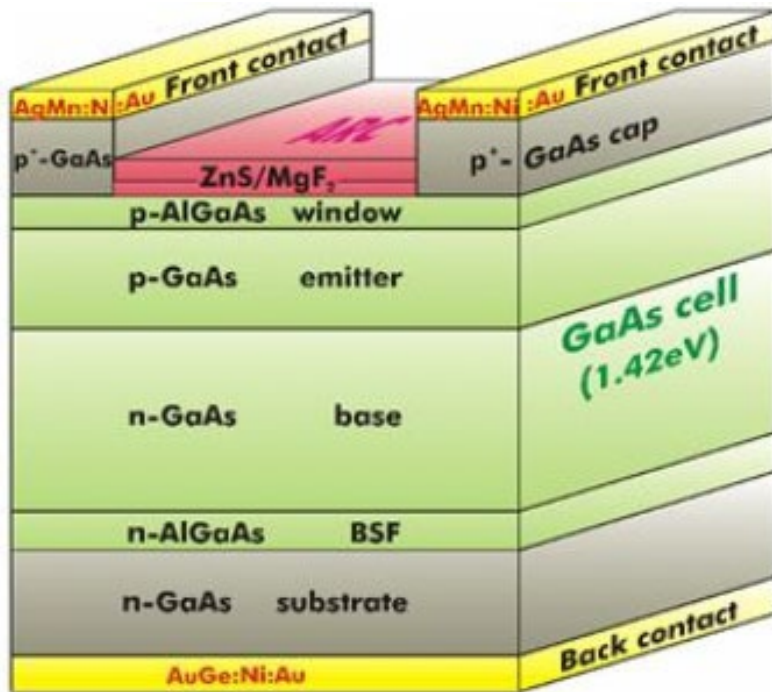


Image from <https://www.tf.uni-kiel.de>

# GaAs single junction cells

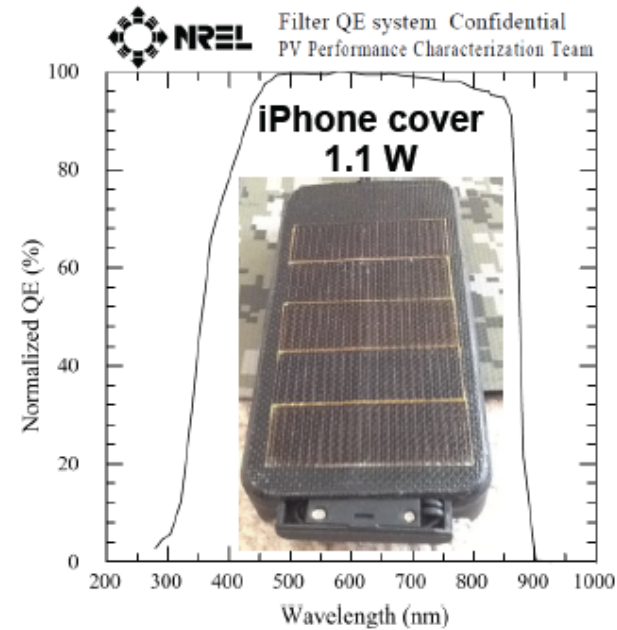
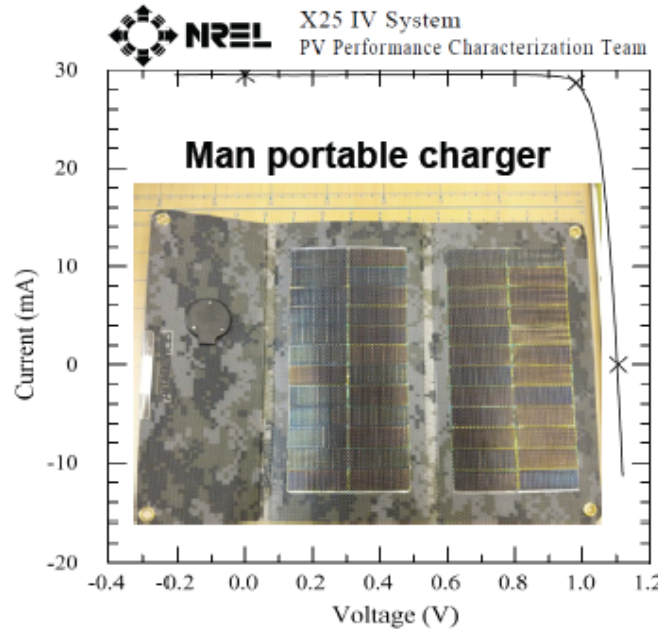


*w/ Bragg reflector*

Source: [http://pvlab.ioffe.ru/about/solar\\_cells.html](http://pvlab.ioffe.ru/about/solar_cells.html)

# GaAs cells from Alta Devices

## Single crystal thin film GaAs solar cells and modules



• Cell efficiency  $\eta = 28.8\%$  @ 1 Sun AM 1.5G

ERE = 48%

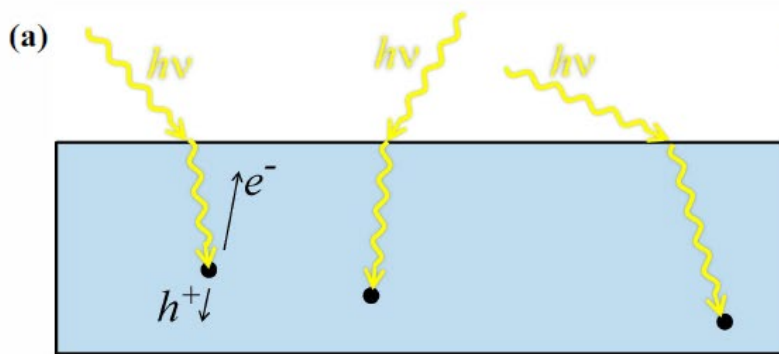
• Module efficiency of 23.2%

• IQE > 0.96

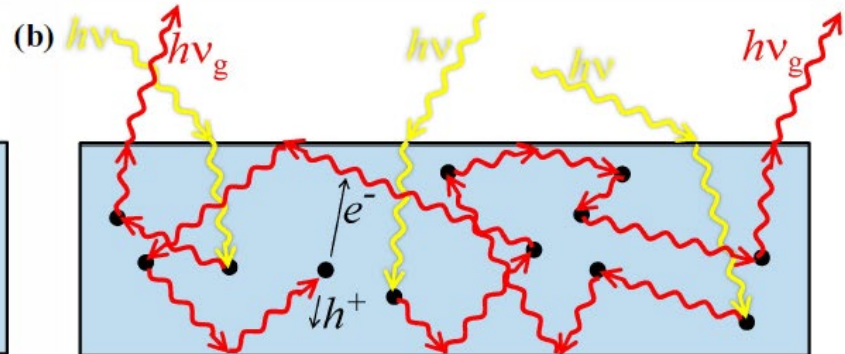
• Economical III-V flat plate (\$1/Wp) PV System)

ALTADEVICES

# Concept of «photon recycling»



«Low» vs

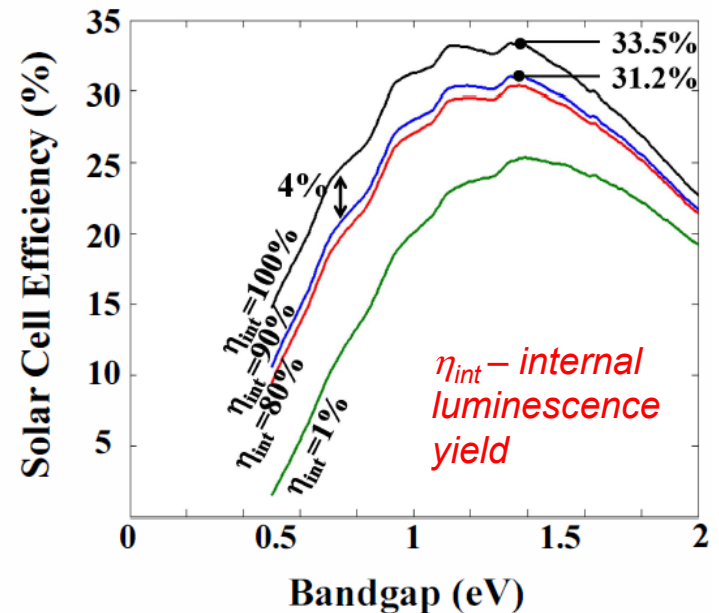


«high» luminescence yield

Reasons for high efficiency in GaAs:

- Optimum bandgap 1.45 eV
- Excellent electronic properties
- High luminescence yield (>99%)

⇒ Good PV material if good LED  
(and vice versa)



# **Multi-junction III-V cells**

# Spectral mismatch for single-junction cells

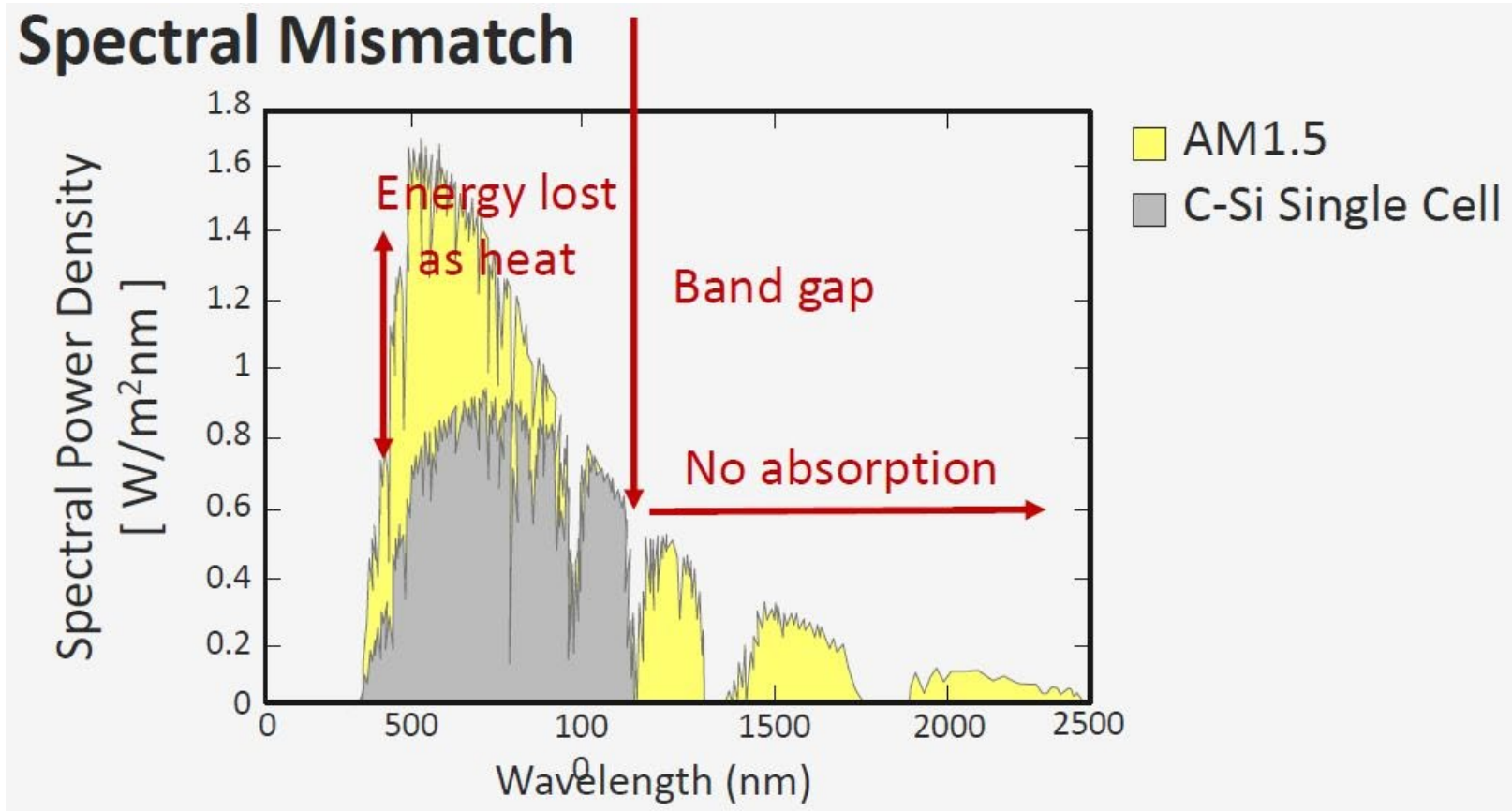
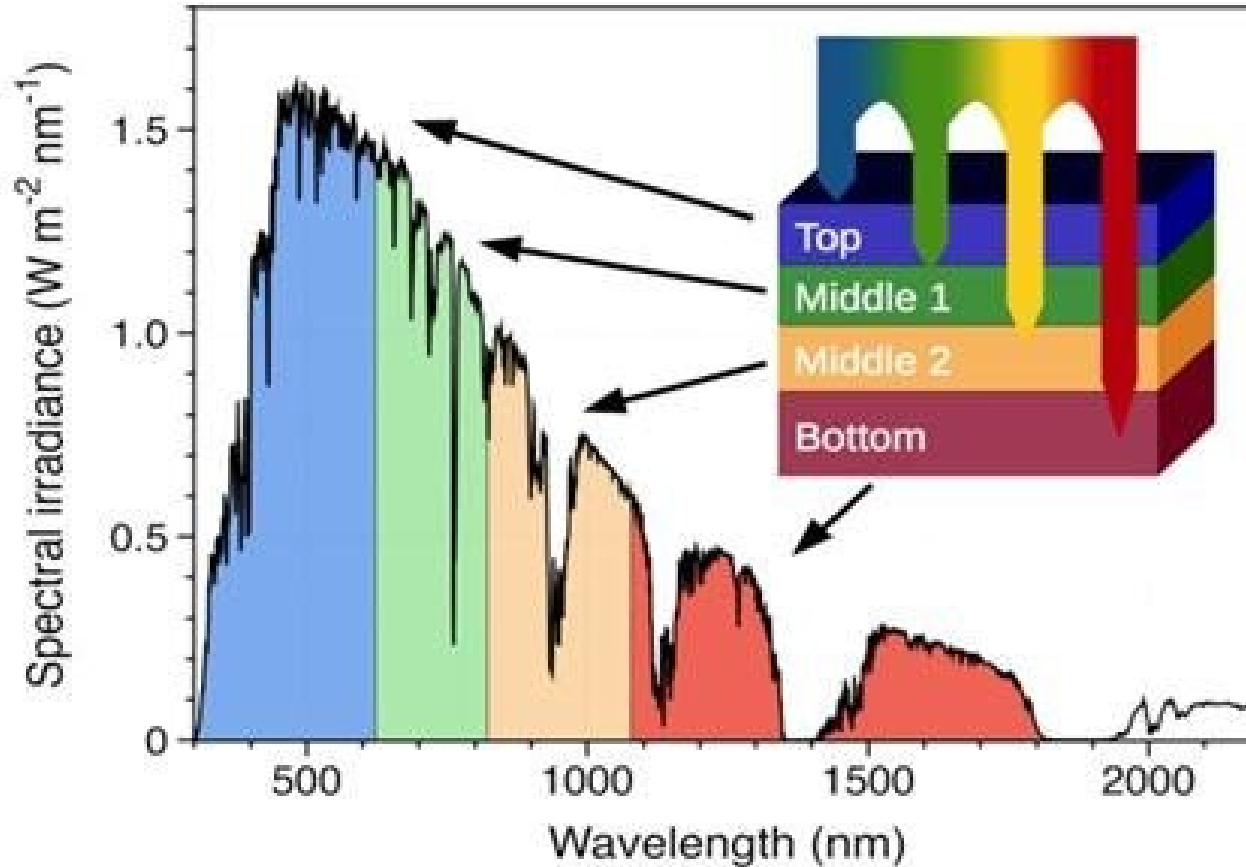


Image from : <http://maxloosolarenergy.blogspot.com/2016/12/spectral-utilization-ii-shockley.html>

- Incomplete utilization of the solar spectrum in single-junction cells limits the maximum efficiency to 33% (S-Q limit)

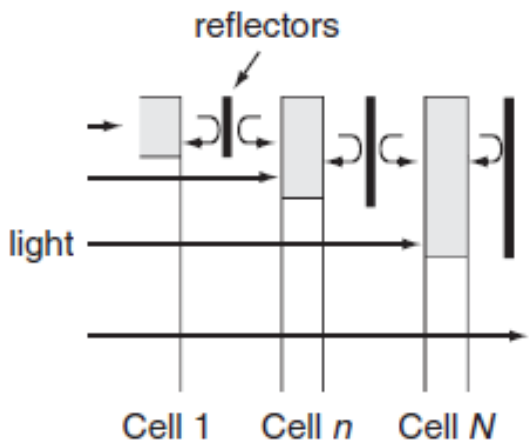


# Multi-junction solar cells



- Better utilization of the solar spectrum in multi-junction cells

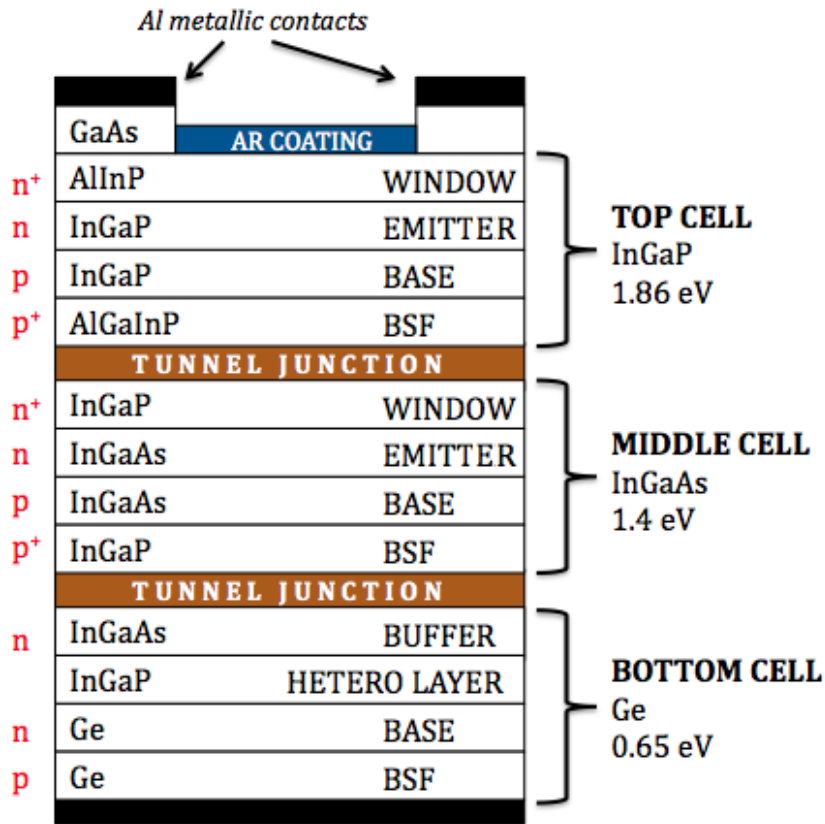
# Maximum efficiency for multi-junction cells



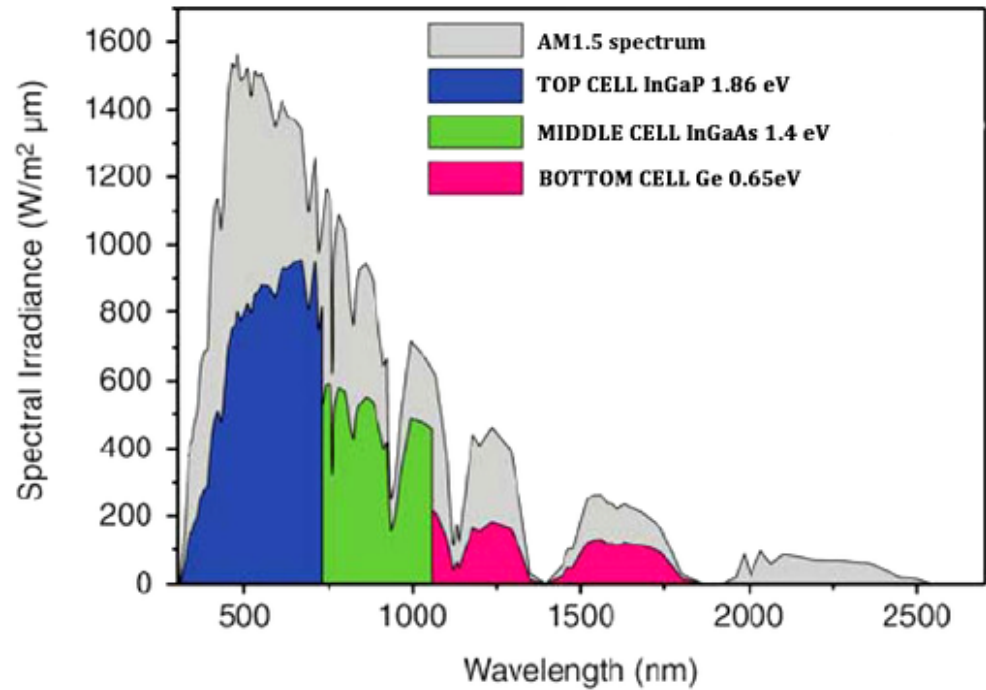
N. cells	Description	Reflectors?	Optimum gaps (eV)				Eff (%)
			$E_1$	$E_2$	$E_3$	$E_4$	
(AM1.5 direct normal irradiance)							
1	1 sun, no angular restriction	Yes	1.13	-	-	-	32.5
	1 sun no angular restriction	No	1.13	-	-	-	32.5
	Maximum concentration	Yes	0.94	-	-	-	44.6
	Maximum concentration	No	0.94	-	-	-	44.6
2	1 sun, no angular restriction	Yes	0.94	1.64	-	-	44.3
	1 sun no angular restriction	No	0.94	1.64	-	-	44.1
	Maximum concentration	Yes	0.71	1.41	-	-	59.7
	Maximum concentration	No	0.71	1.41	-	-	59.4
3	1 sun, no angular restriction	Yes	0.71	1.16	1.83	-	50.1
	1 sun no angular restriction	No	0.71	1.16	1.83	-	49.7
	Maximum concentration	Yes	0.69	1.16	1.84	-	67.0
	Maximum concentration	No	0.69	1.16	1.83	-	66.6
4	1 sun, no angular restriction	Yes	0.71	1.13	1.55	2.13	54.0
	1 sun no angular restriction	No	0.71	1.13	1.55	2.13	53.6
	Maximum concentration	Yes	0.53	1.13	1.55	2.13	71.0
	Maximum concentration	No	0.53	1.13	1.55	2.13	70.7
$\infty$	1 sun, no angular restriction	Yes	-	-	-	-	65.4
	1 sun no angular restriction	No	-	-	-	-	65.4
	Maximum concentration	Yes	-	-	-	-	85.0
	Maximum concentration	No	-	-	-	-	85.0

Marti & Araujo, SOLMAT 1996

# Triple-junction cells based on III-V



(a)



(b)

Image: [www.Wikipedia.com](http://www.Wikipedia.com)

# Structure of a triple-junction III-V cell

Monolithic  
interconnection  
with tunnel junctions

		materials parameters (typical/illustrative):		
		material	bandgap (eV)	thickness ( $\mu\text{m}$ )
top subcell	top contact	Ag		3
	contacting layer ( $\text{n}^{++}$ )	Ga(In)As	1.39	0.5
	antireflection coat	$\text{TiO}_2/\text{Al}_2\text{O}_3$		0.2
	window ( $\text{n}$ )	AlInP	2.3	0.03
	emitter ( $\text{n}^+$ )	GaInP	1.85	0.1
tunnel junction	base ( $\text{p}$ )	GaInP	1.85	0.5 to 1.5
	back-surface field ( $\text{p}$ )	AlGaInP	1.88	0.1
middle subcell	$\text{p}^{++}$	AlGaAs	1.9	0.1
	$\text{n}^{++}$	GaInP	1.9	0.1
	window ( $\text{n}$ )	GaInP	1.85	0.1
	emitter ( $\text{n}$ )	Ga(In)As	1.39	0.1
	base ( $\text{p}$ )	Ga(In)As	1.39	3
tunnel junction	back-surface field ( $\text{p}$ )	GaInP	1.85	0.1
	$\text{p}^{++}$	AlGaAs	1.9	0.1
	$\text{n}^{++}$	GaInP	1.9	0.1
	window ( $\text{n}$ )	GaInP	1.85	0.1
	emitter ( $\text{n}^+$ )	Ge (P-diffused)	0.67	0.05
bottom subcell	base ( $\text{p}$ )	Ge (substrate)	0.67	200
	back-surface field ( $\text{p}$ )	none		
	back contact	Ag		

# Tunnel junction

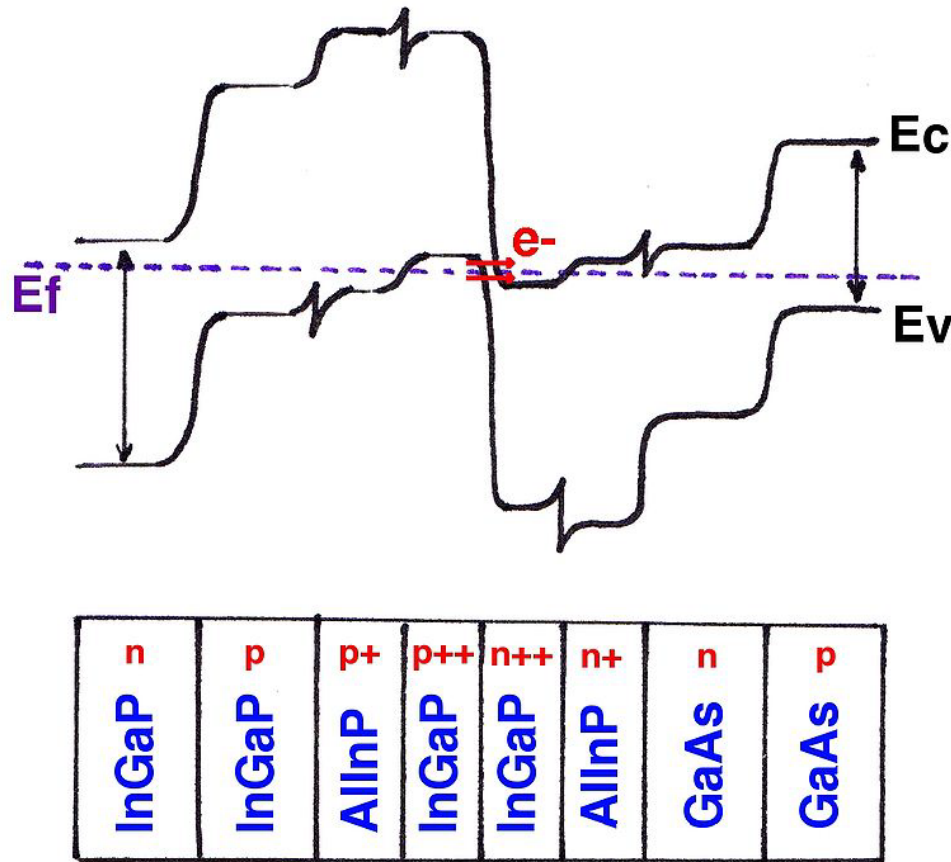
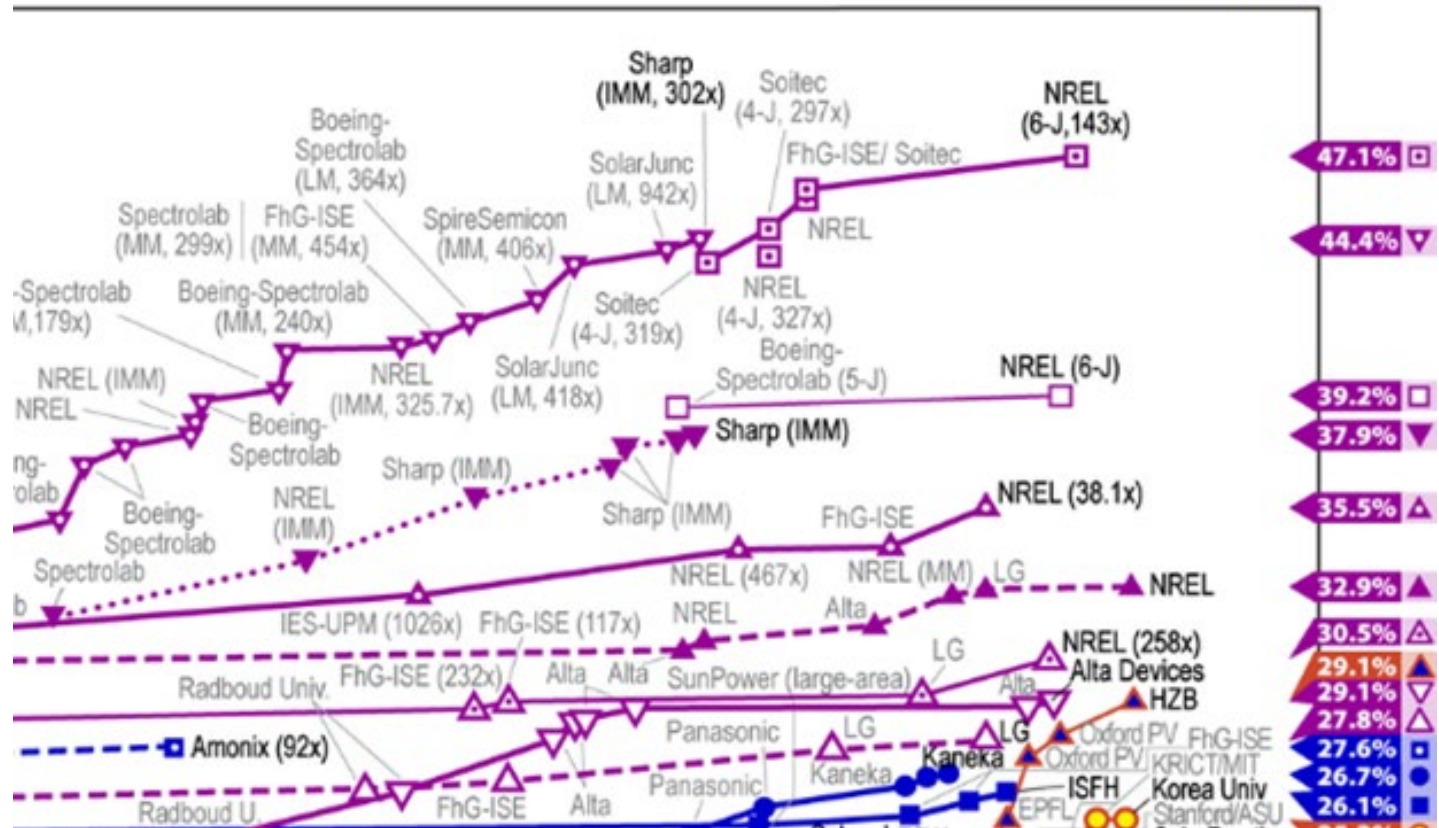


Image: [www.Wikipedia.com](http://www.Wikipedia.com)

- Tunnel junctions provide a low electrical resistance between two subcells
- Must be optically transparent

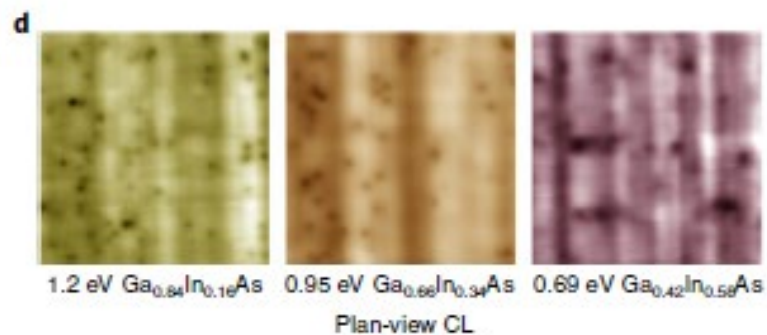
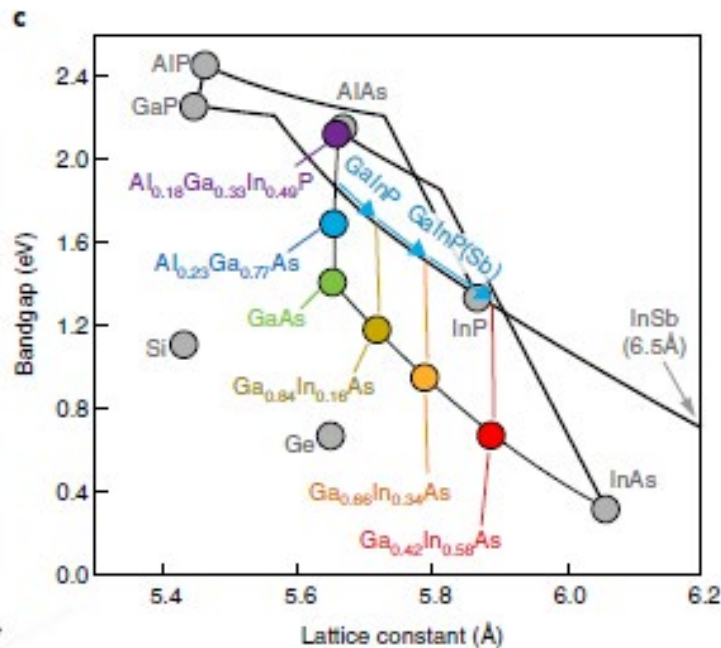
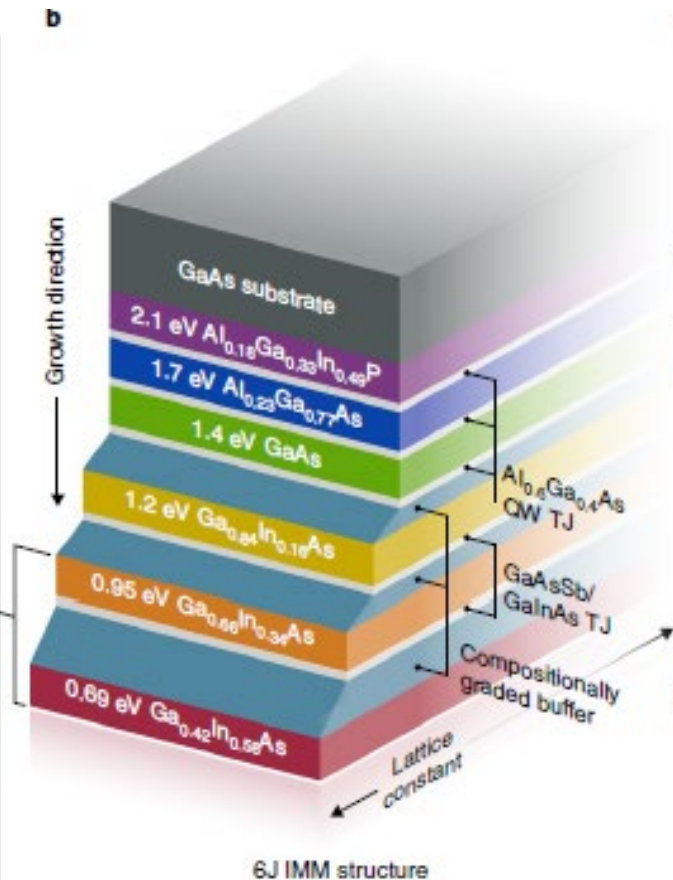
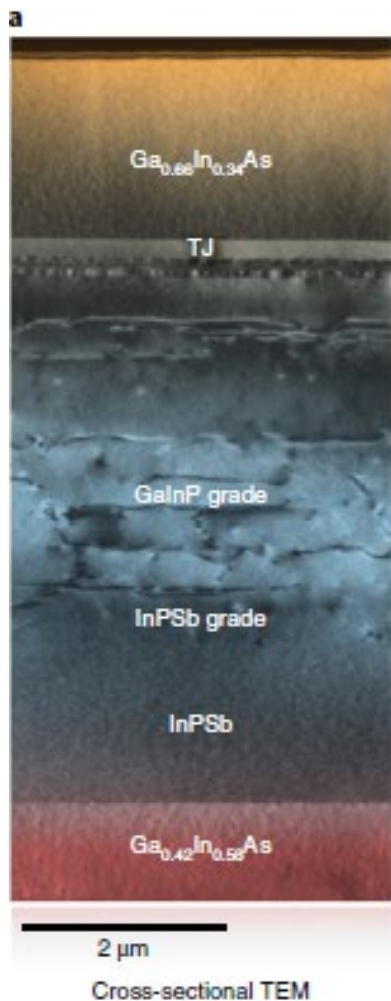
# Efficiency of III-V multi-junction cells



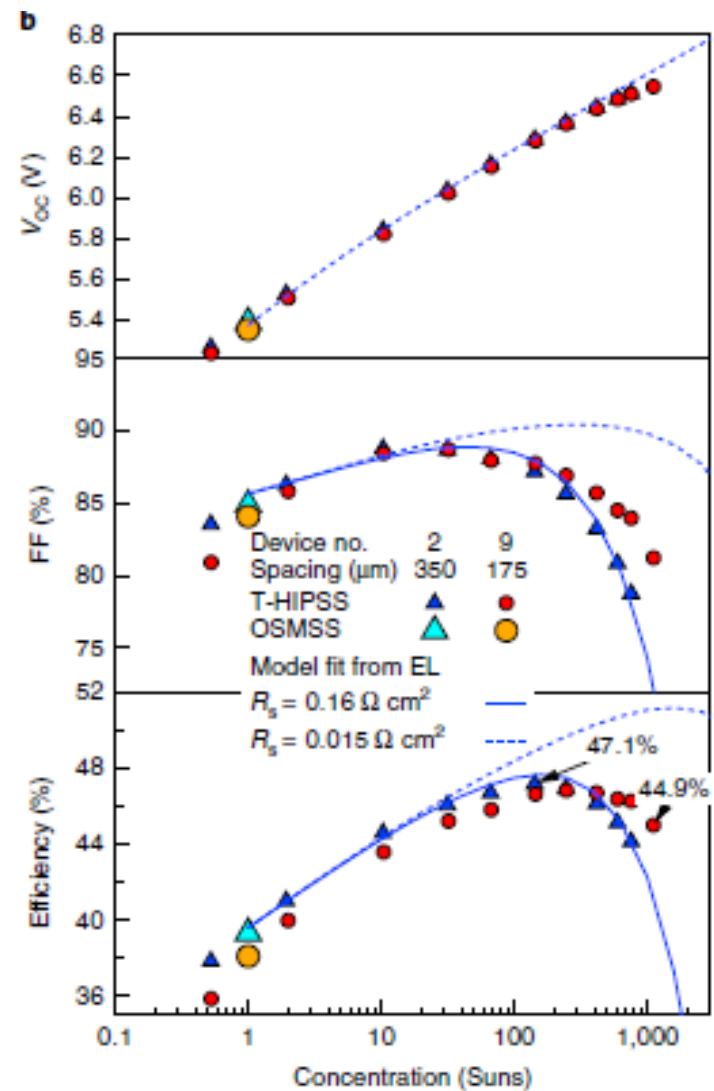
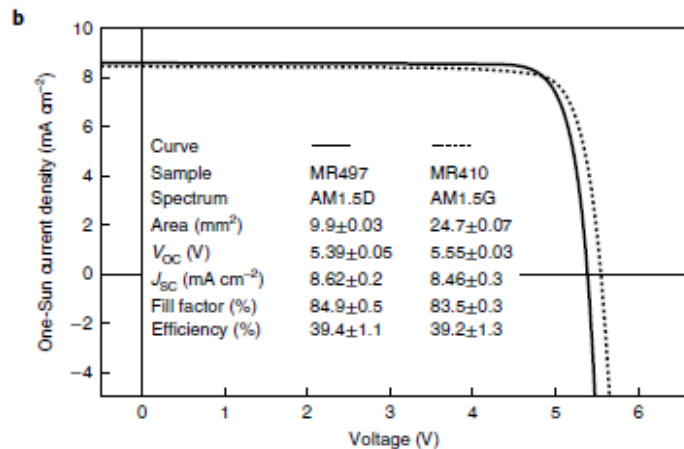
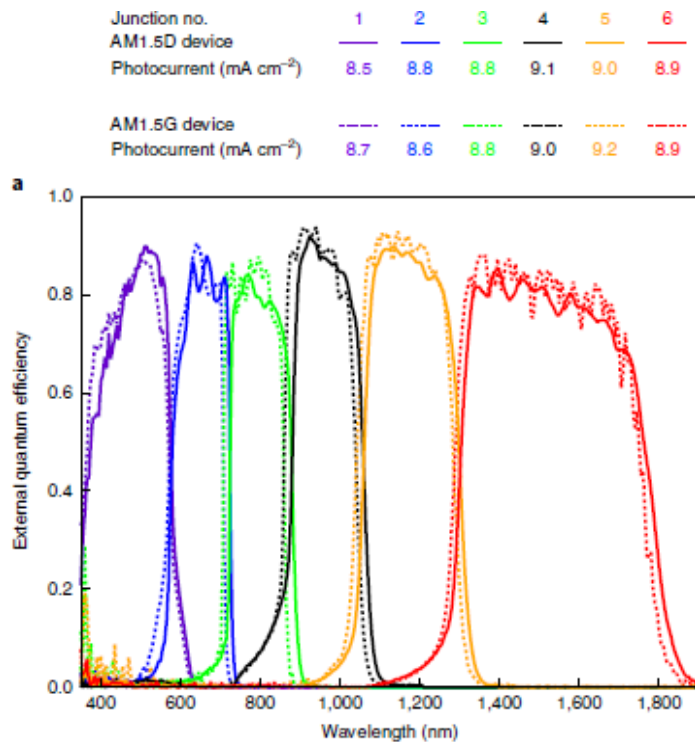
- GaAs-based solar cells are the most efficient
- Highest efficiencies up to 47% are measured under concentrated light

Source: NREL, June 2022

# World record solar cell x6 junction cell



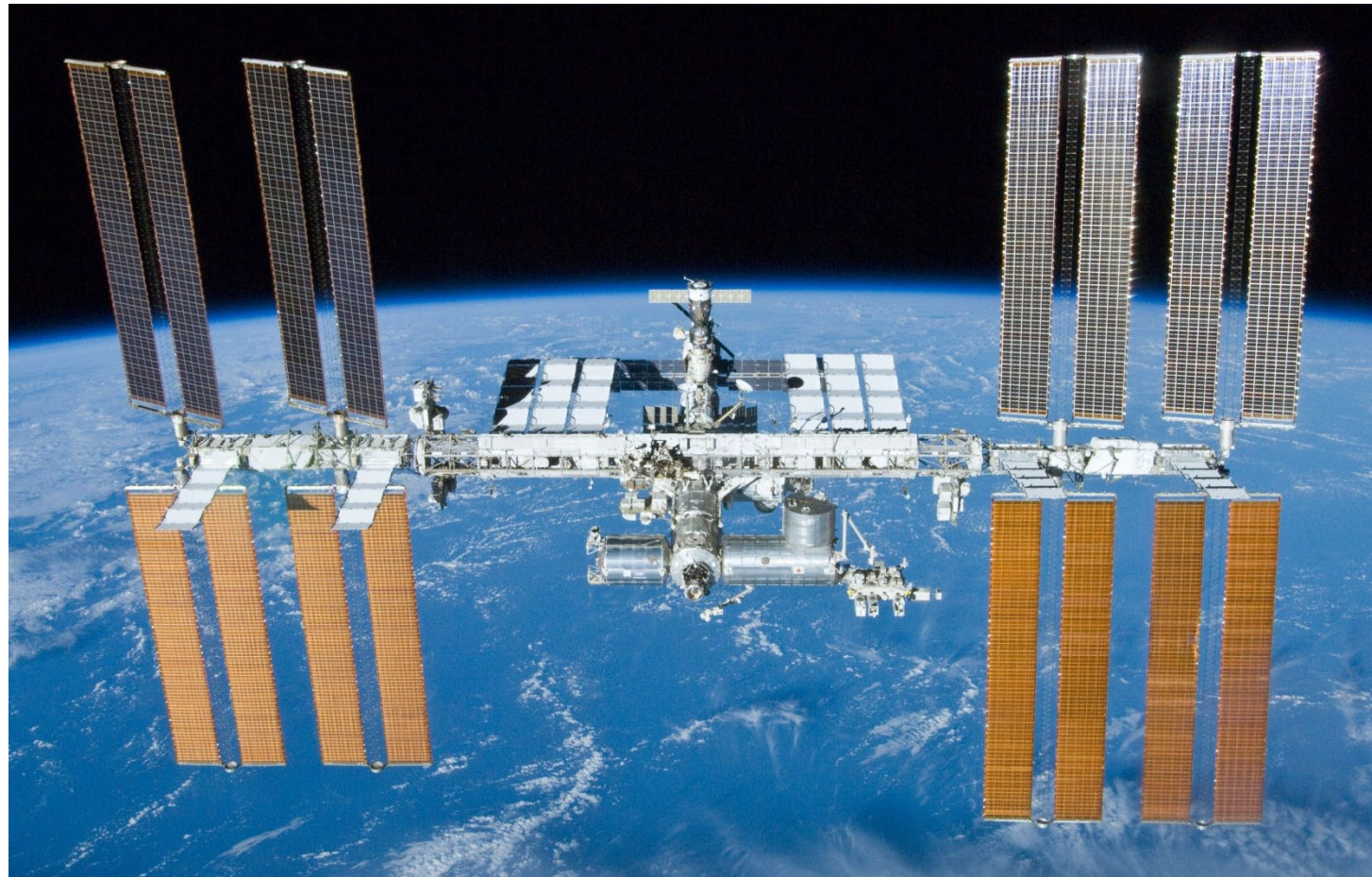
# World record 47.1% efficiency under 143 Suns concentration





# **Solar cells for space**

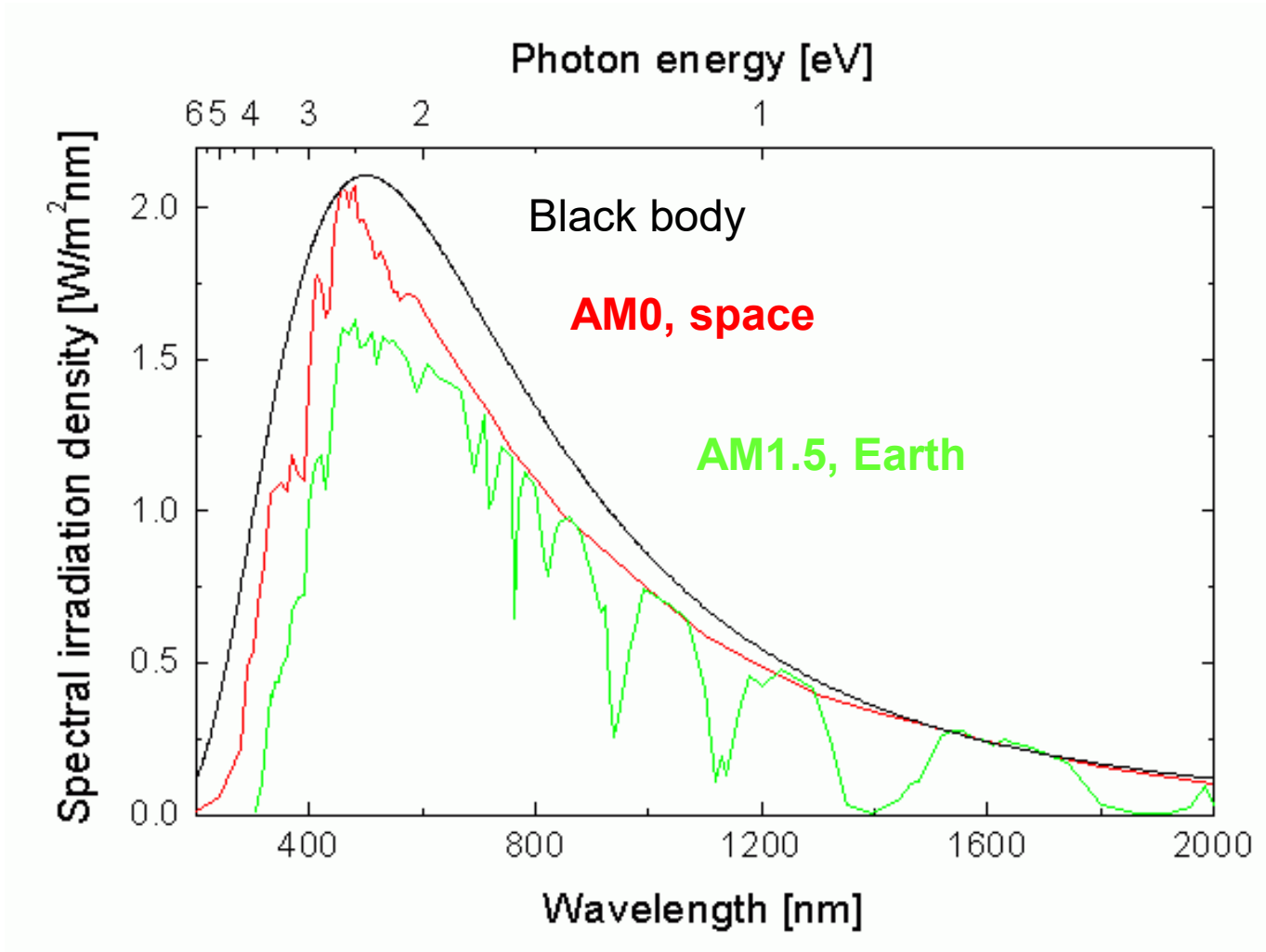
# Solar Power Generation in Space



Vanguard 1  
(USA, 1958 - 1964)

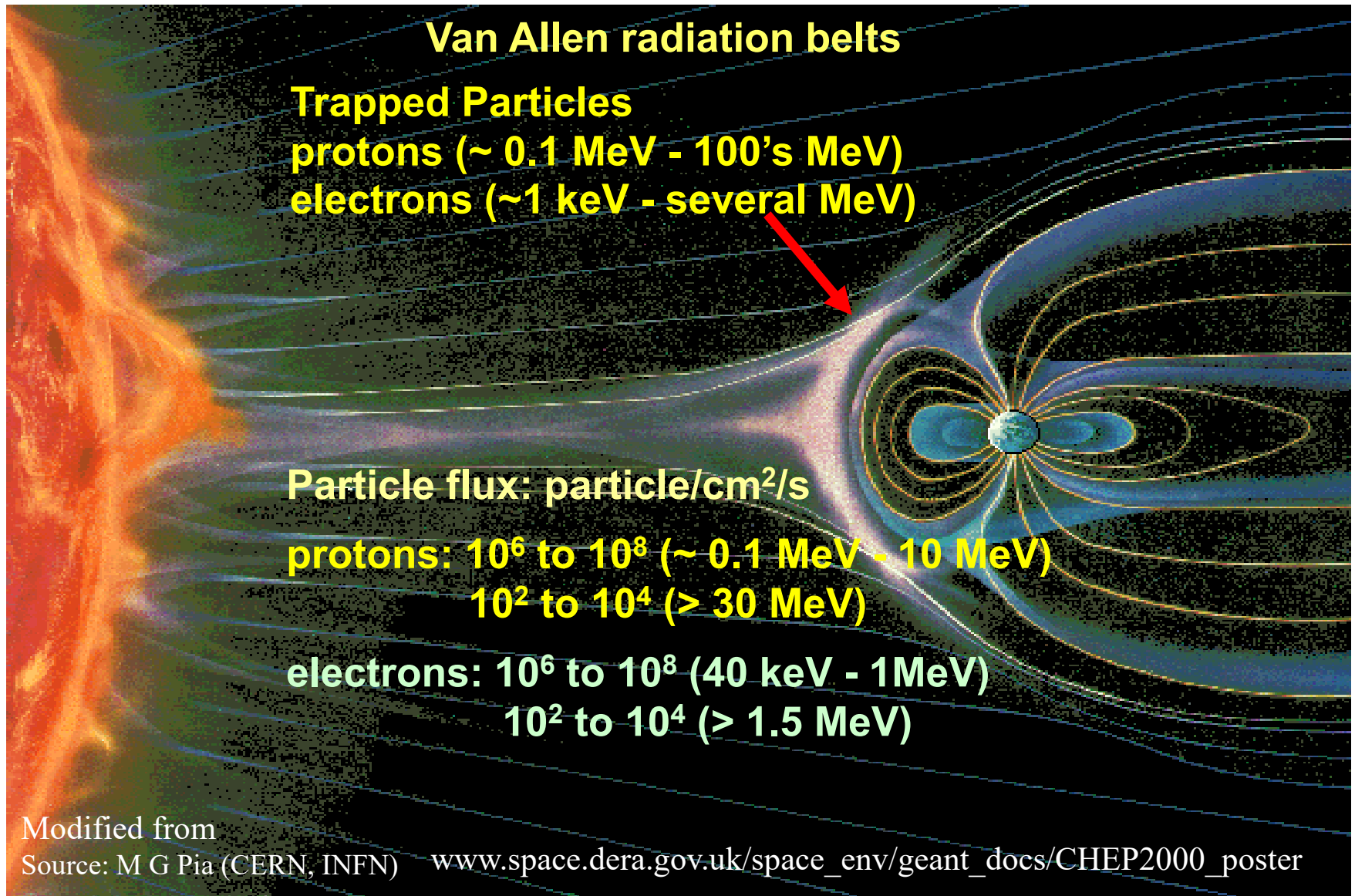
International Space Station (ISS), 1998-

# Solar radiation in space

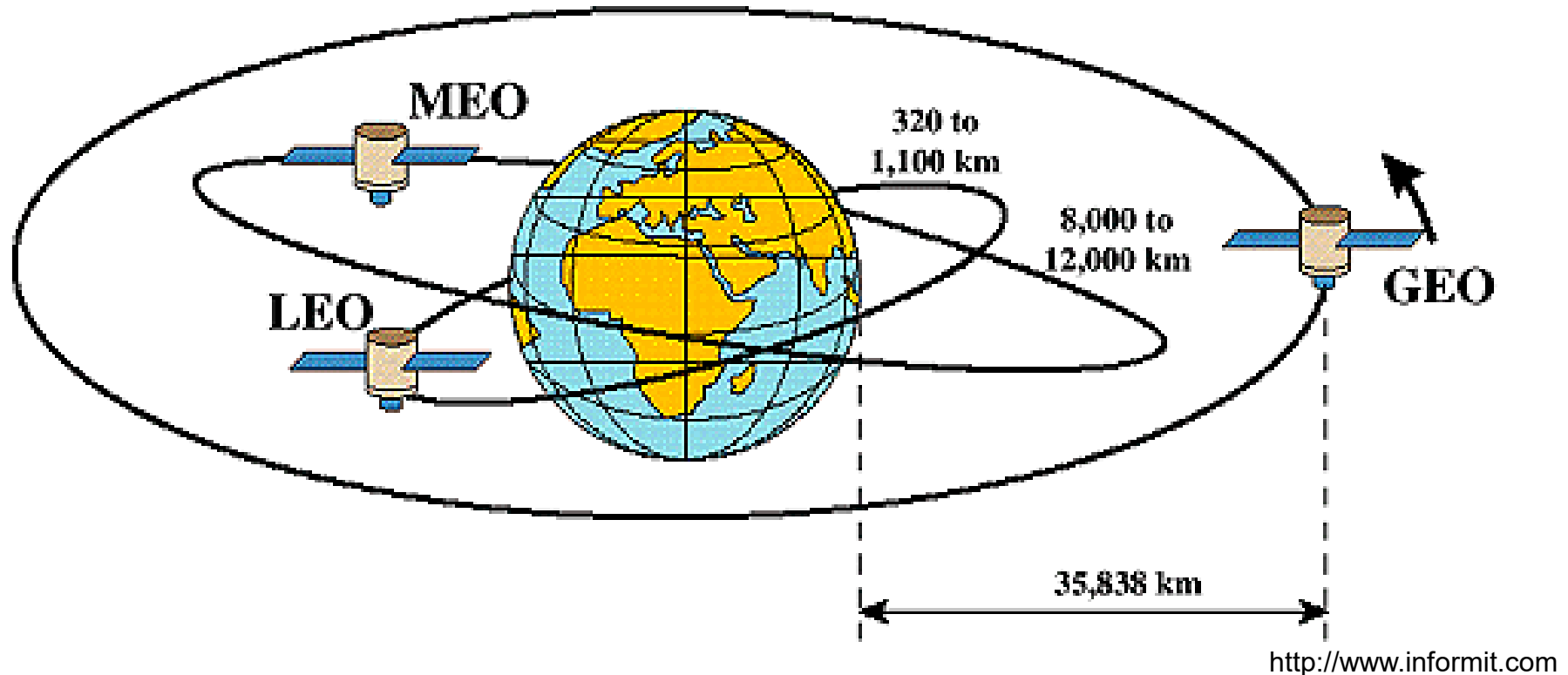


AM0 solar spectrum in space (outside Earth's atmosphere): 1353 W/m<sup>2</sup>

# Particle fluxes near the Earth



# Satellite orbits

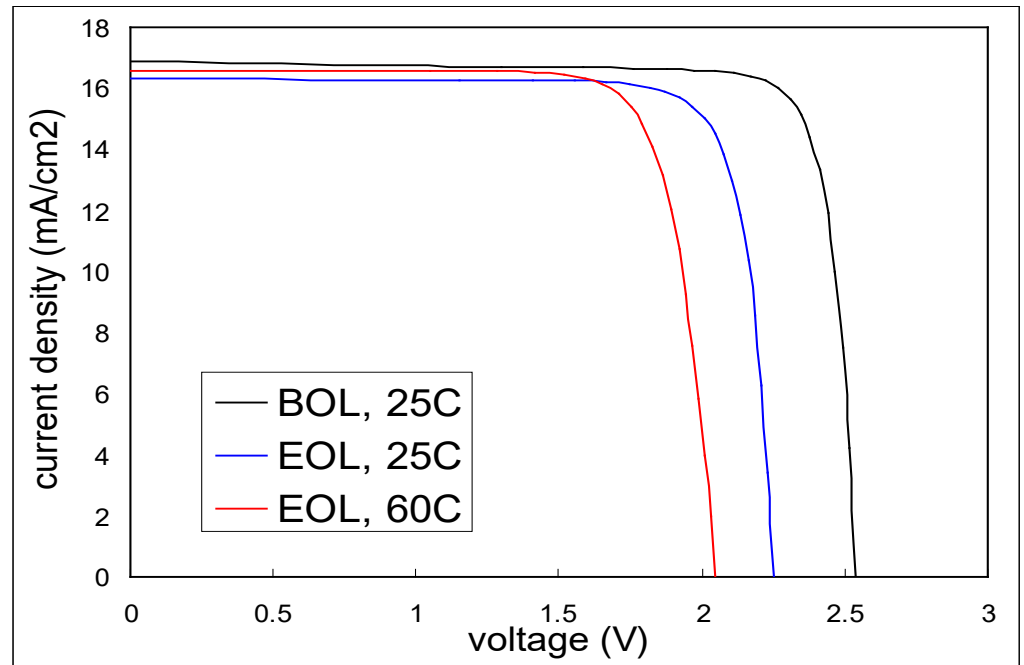


- PV power requirement for a telecom satellite~ 10kW
- Weight 20...200 kg (array specific power 45W/kg)
- can add \$1....10 Mio\$ to the launch cost for GEO

# Cell degradation in space

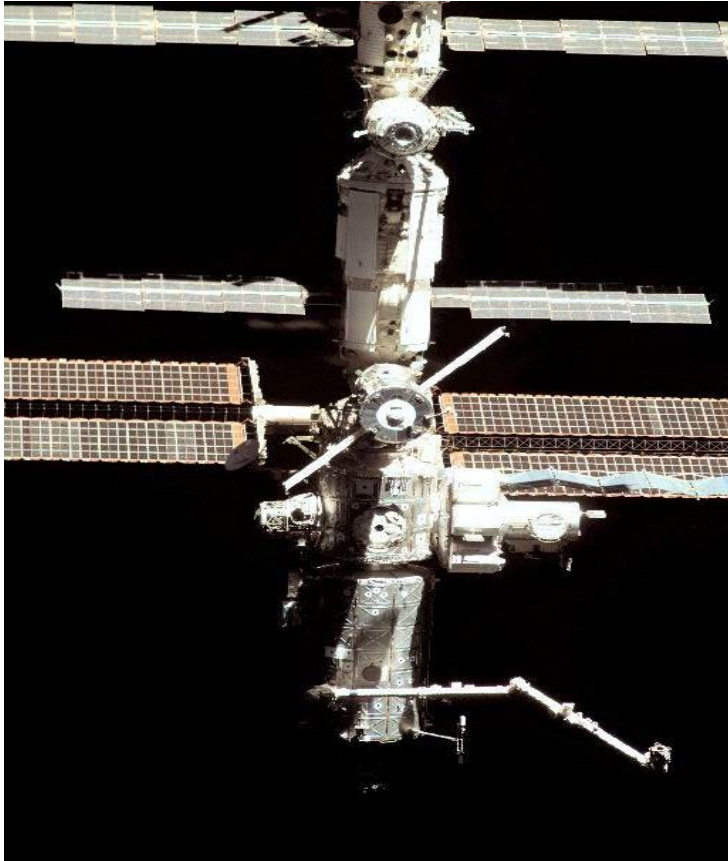
## Efficiency degradation in space due to electron and proton irradiation

- Degradation of solar cell performance due to defect generation in the semiconducting layers.
- Elevated temperatures reduce the voltage, FF and increase the current.



Spectrolab 3J GaAs

# III-V multi-junction cells for space



S108E9634\_2001:12:15 16:25:29

Spectrolab NeXt Triple Junction (XTJ) cells  
Efficiency: 29.5%



## **Radiation Degradation** (Fluence 1MeV Electrons/cm<sup>2</sup>)

Parameters	1x10 <sup>14</sup>	5x10 <sup>14</sup>	1x10 <sup>15</sup>
I <sub>mp</sub> /I <sub>mp0</sub>	1.00	0.99	0.95
V <sub>mp</sub> /V <sub>mp0</sub>	0.94	0.91	0.89
P <sub>mp</sub> /P <sub>mp0</sub>	0.95	0.90	0.85

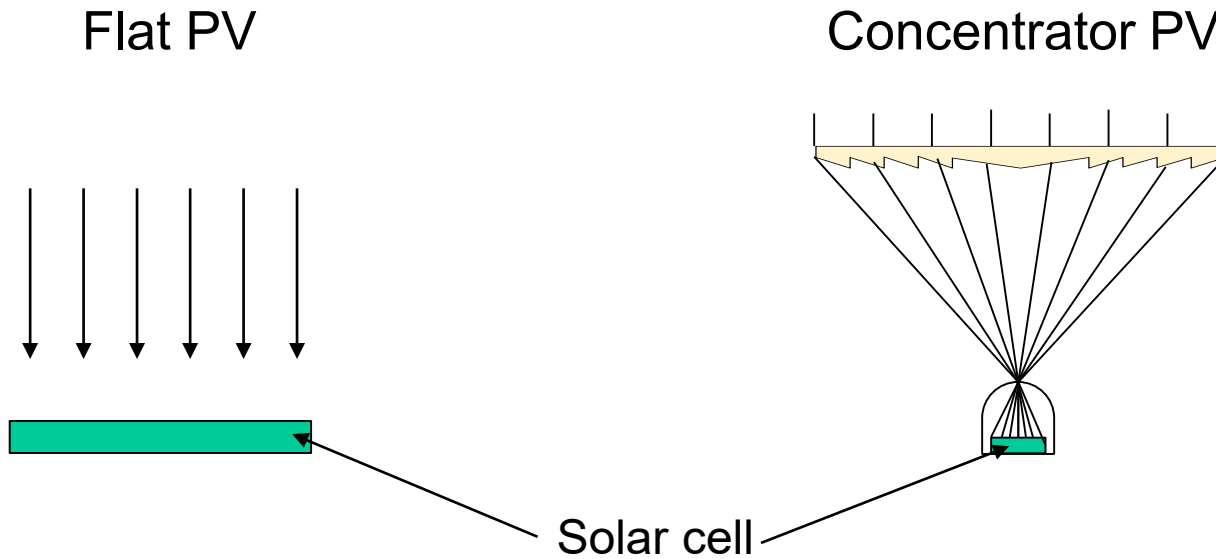
# **Concentrator PV (CPV)**

(not to be confused with  
concentrator solar power CSP)



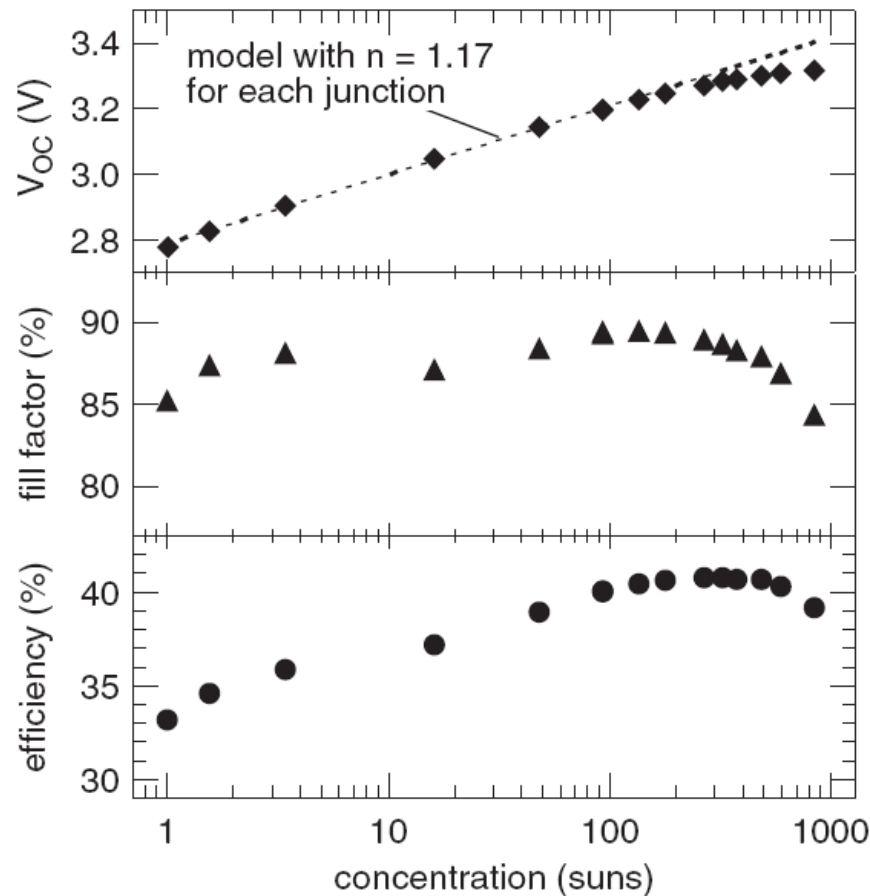
# Why concentrator photovoltaics?

Reduce solar cell area by using optical concentration: up to ~1000 suns



Replace solar cell material (expensive) by optics (cheaper?)

# Solar parameters under concentrated light

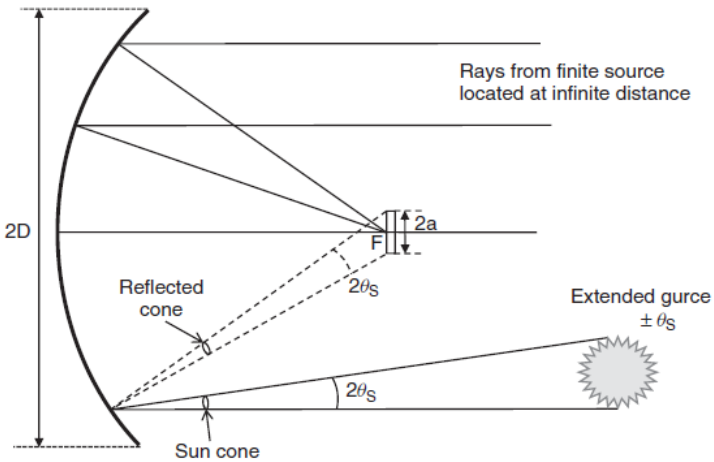


$$V_{oc} \approx \frac{kT}{q} \ln\left(\frac{I_L}{I_0}\right)$$

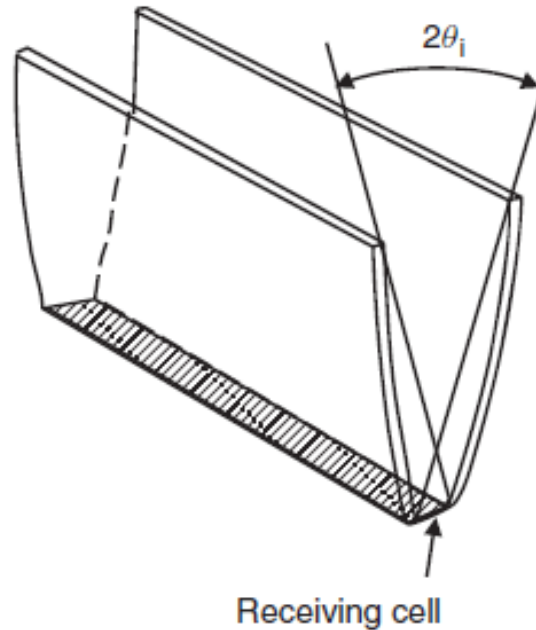
**Figure 8.12** Efficiency,  $V_{oc}$ , and fill factor of state-of-the-art GaInP/Ga<sub>0.96</sub>In<sub>0.04</sub>As/Ga<sub>0.63</sub>In<sub>0.37</sub>As three-junction cell as a function of concentration.  $J_{sc}$ , not shown, is assumed to increase proportionally to concentration

# Light concentrators

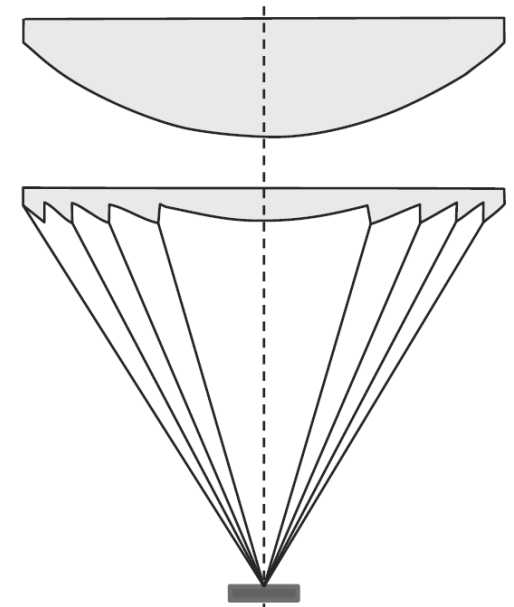
## Parabolic mirror concentrator



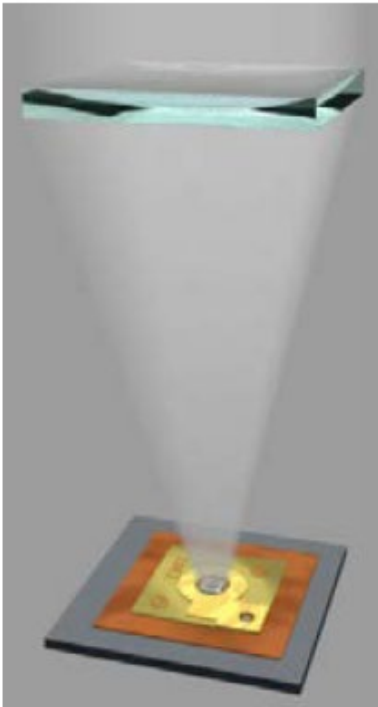
## Compound parabolic concentrator



## Fresnel lenses

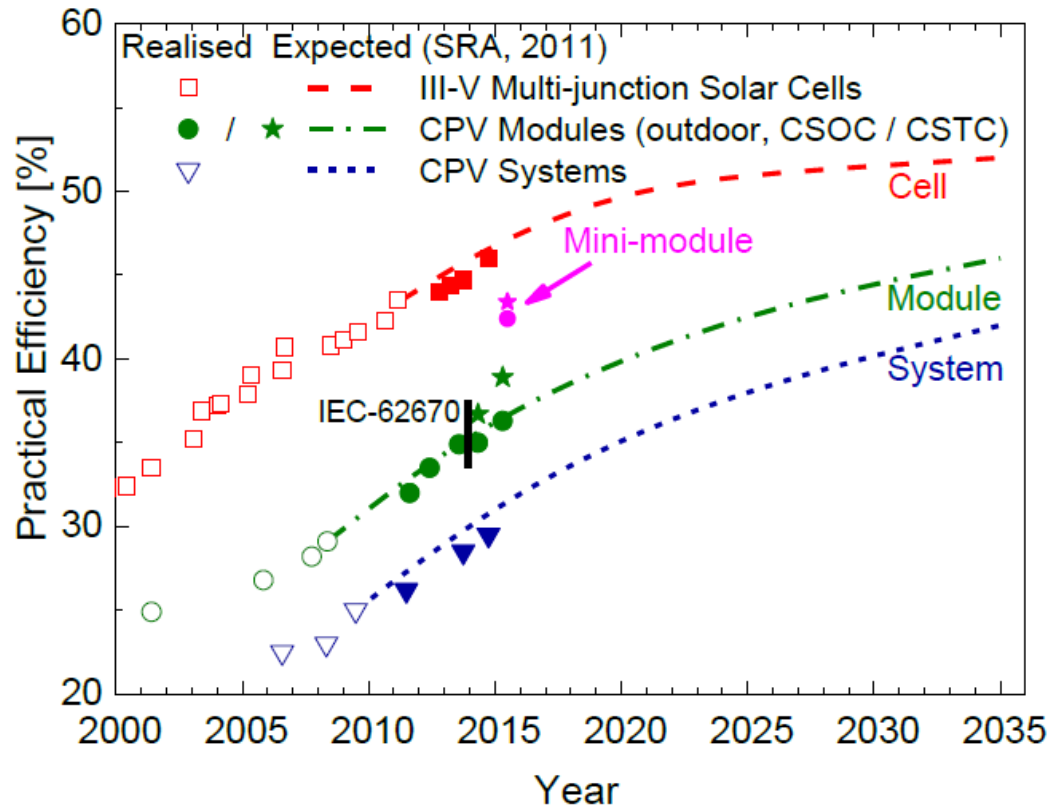


# Light concentrating systems



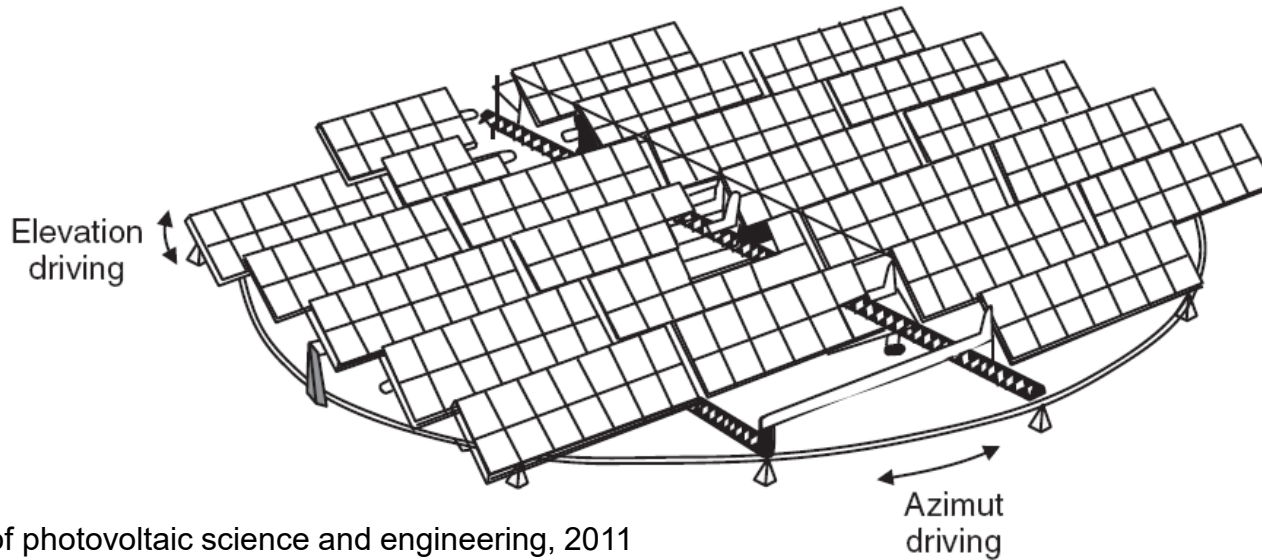
<b>Class of CPV</b>	<b>Typical concentration ratio</b>	<b>Tracking</b>	<b>Type of converter</b>
High Concentration PV (HCPV)	300-1000	Two-axis	III-V multi-junction solar cells
Low Concentration PV (LCPV)	< 100	One or two-axis	c-Si or other cells

# CPV efficiency



- Certified record value for solar cell efficiency of 47.1% (NREL, 2020)
- 38.9% module efficiency of 38.9 % (Soitec)

# Light-tracking systems

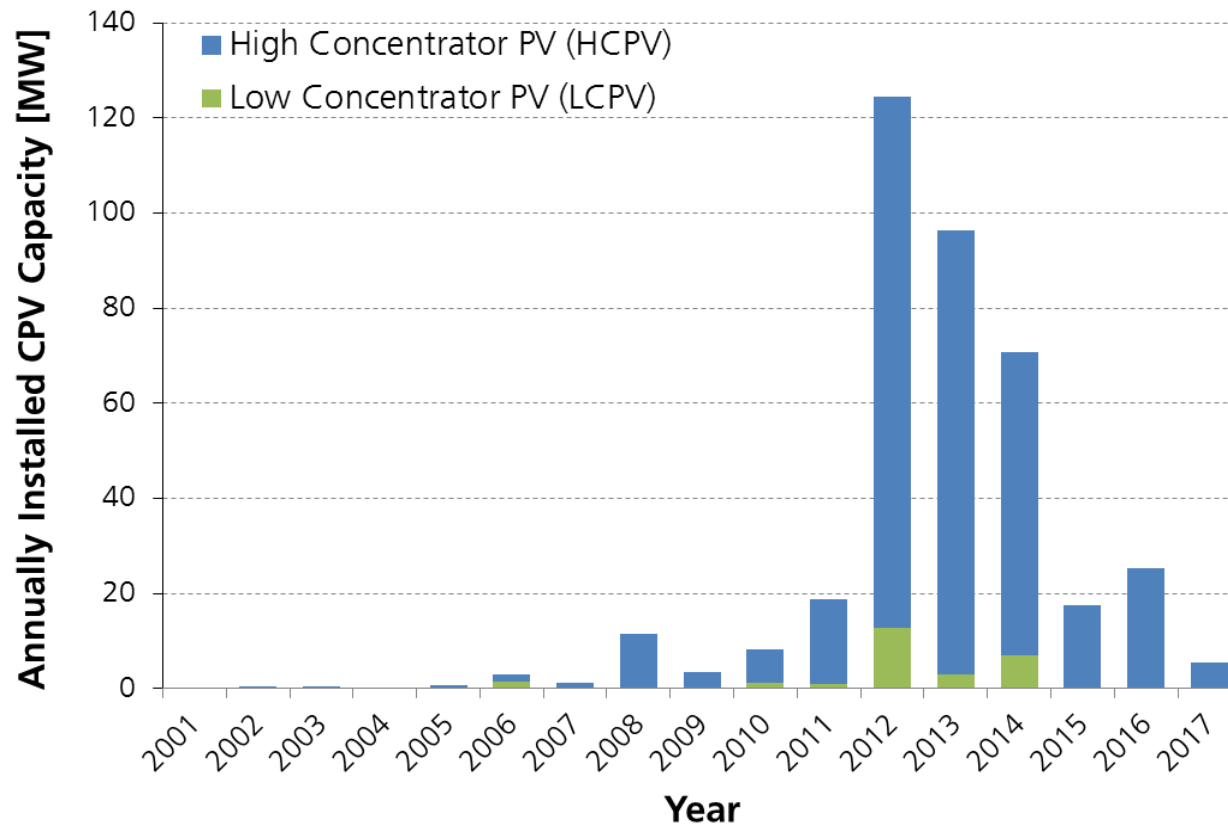


Handbook of photovoltaic science and engineering, 2011



30 MW plant in Alamosa, Colorado, USA (© Amonix)

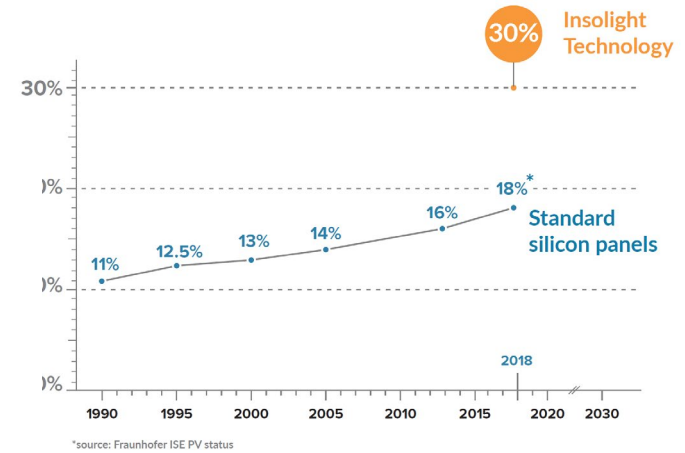
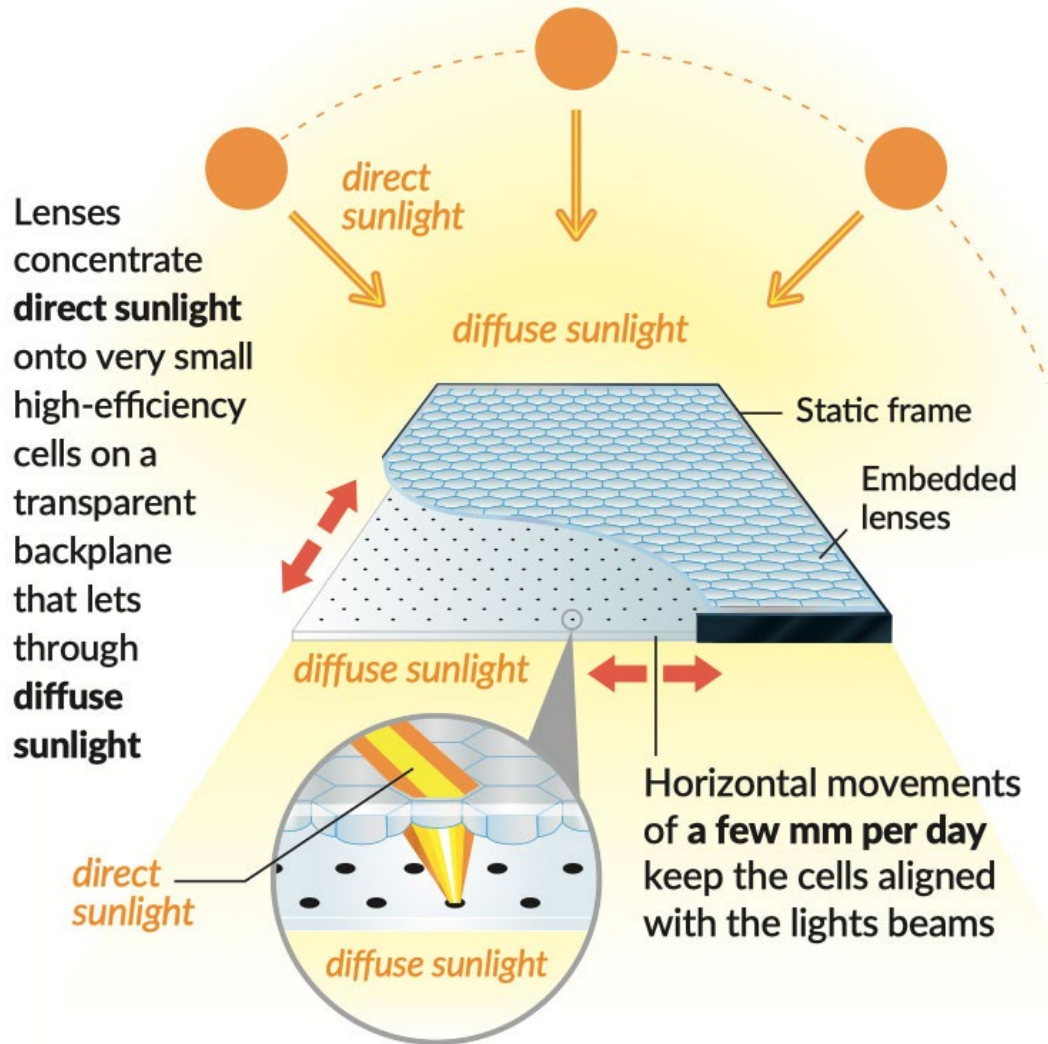
# CPV installations



“Current status of concentrator photovoltaic (CPV) technology” report, ISE and NREL, 2018

- Cumulative worlds installations: 360 MW (only 0.1% of total PV)
- Worldwide manufacturing capacities have strongly decreased in 2015 due to the closure of Soitec’s and Suncore’s manufacturing facilities.

# Insolight (Swiss made)



<https://insolight.ch/technology/>